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MM74C164 8-Bit Parallel-Out Serial Shift Register

FAIRCHILD

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MM74C164 8-Bit Parallel-Out Serial Shift Register

General Description

The MM74C164 shift registers are a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. These 8-bit shift registers have gated serial inputs and clear. Each register bit is a D-type master/slave flip-flop. A high-level input enables the other input which will then determine the state of the flip-flop.

Data is serially shifted in and out of the 8-bit register during the positive going transition of clock pulse. Clear is independent of the clock and accomplished by a low level at the clear input. All inputs are protected against electrostatic effects.

Features

- Supply voltage range: 3V to 15V
- Tenth power TTL compatible: drive 2 LPTTL loads
- High noise immunity: 0.45 V_{CC} (typ.)
- Low power: 50 nW (typ.)
- Medium speed operation: 0.8 MHz (typ.) with 10V supply

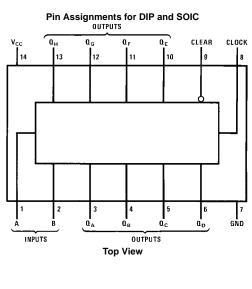
Applications

- Data terminals
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering
- Computers

Ordering Code:

Order Number	Package Number	Package Description
MM74C164M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
MM74C164N N14A 14-Lead Plas		14-Lead Plastic Dual-In-Line (PDIP), JEDEC MS-001, 0.300" Wide
Devices also available	in Tape and Reel. Specify	by appending the suffix letter "X" to the ordering code.

Connection Diagram

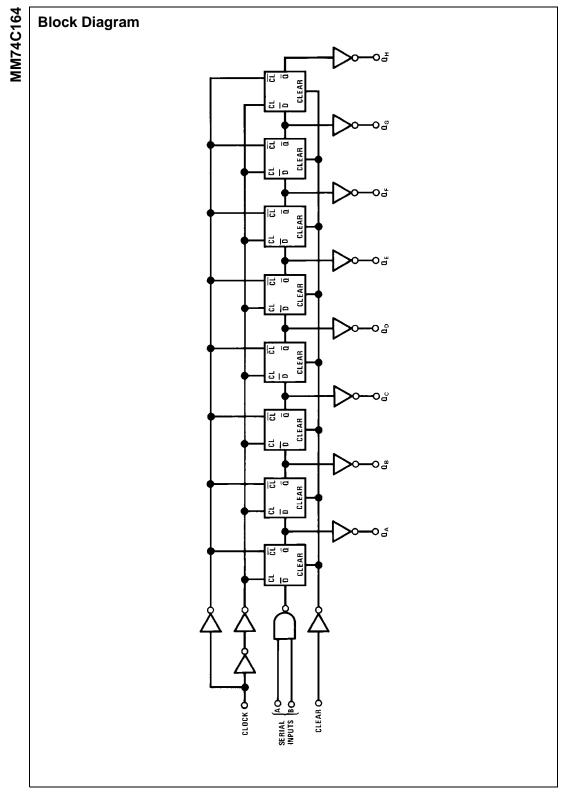


Truth Table

Serial Inputs A and B

Inp	Output		
t	t _{n+1}		
A B		Q _A	
1	1	1	
0	1	0	
1	0	0	
0	0	0	

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Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	–0.3V to V_{CC} + 0.3V
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Absolute Maximum V _{CC}	18V
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW

Operating V_{CC} Range Lead Temperature (soldering, 10 seconds) MM74C164

3V to 15V

260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

DC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO	смоз		I			
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5V$	3.5			V
		$V_{CC} = 10V$	8.0			V
V _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5V$			1.5	V
		$V_{CC} = 10V$			2.0	V
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \ \mu A$	4.5			V
		$V_{CC} = 10V$, $I_{O} = -10 \ \mu A$	9.0			V
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 5V, I_{O} = +10 \ \mu A$			0.5	V
		$V_{CC} = 10V$, $I_{O} = +10 \ \mu A$			1.0	V
I _{IN(1)}	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$		0.005	1.0	μA
I _{IN(0)}	Logical "0" Input Current	V _{CC} = 15V, V _{IN} = 0V	-1.0	-0.005		μΑ
Icc	Supply Current	$V_{CC} = 15V$		0.05	300	μA
CMOS TO	LPTTL INTERFACE					
V _{IN(1)}	Logical "1" Input Voltage	V _{CC} = 4.75V	V _{CC} – 1.5			V
V _{IN(0)}	Logical "0" Input Voltage	V _{CC} = 4.75V			0.8	V
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 4.75 V$, $I_{O} = -360 \ \mu A$	2.4			V
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 4.75 V$, $I_{O} = 360 \ \mu A$			0.4	V
	RIVE (See Family Characteristics	Data Sheet) (Short Circuit Current)				
ISOURCE	Output Source Current	$V_{CC} = 5V, V_{IN(0)} = 0V$	-1.75			mA
		$T_A = 25^{\circ}C, V_{OUT} = 0V$				
ISOURCE	Output Source Current	$V_{CC} = 10V, V_{IN(0)} = 0V$	-8.0			mA
		$T_A = 25^{\circ}C, V_{OUT} = 0V$				
I _{SINK}	Output Sink Current	$V_{CC} = 5V, V_{IN(1)} = 5V$	1.75			mA
		$T_A = 25^{\circ}C, V_{OUT} = V_{CC}$				
I _{SINK}	Output Sink Current	$V_{CC} = 10V, V_{IN(1)} = 10V$	8.0			mA
		$T_A = 25^{\circ}C, V_{OUT} = V_{CC}$				

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AC Electrical Characteristics (Note 2)

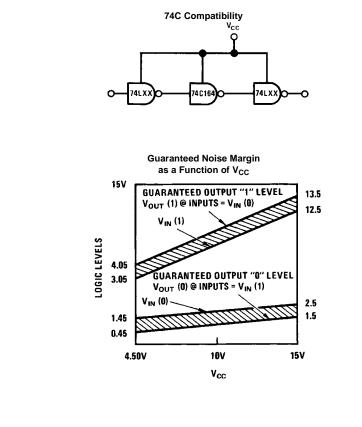
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{pd1}	Propagation Delay Time to a Logical "0" or a	$V_{CC} = 5V$		230	310	ns
	Logical "1" from Clock to Q	$V_{CC} = 10V$		90	120	ns
t _{pd0}	Propagation Delay Time to a Logical "0" from	$V_{CC} = 5V$		280	380	ns
	Clear to Q	$V_{CC} = 10V$		110	150	ns
ts	Time Prior to Clock Pulse that Data	$V_{CC} = 5V$	200	110		ns
	Must be Present	$V_{CC} = 10V$	80	30		ns
t _H	Time After Clock Pulse that	$V_{CC} = 5V$	0	0		ns
	Data Must be Held	$V_{CC} = 10V$	0	0		ns
f _{MAX}	Maximum Clock Frequency	$V_{CC} = 5V$	2.0	3		MHz
		$V_{CC} = 10V$	5.5	8		MHz
t _W	Minimum Clear Pulse Width	$V_{CC} = 5V$		150	250	ns
		$V_{CC} = 10V$		55	90	ns
t _r , t _f	Maximum Clock Rise and Fall Time	$V_{CC} = 5V$	15			μs
		$V_{CC} = 10V$	5			μs
C _{IN}	Input Capacitance	Any Input (Note 3)		5		pF
CPD	Power Dissipation Capacitance	(Note 4)		140		pF

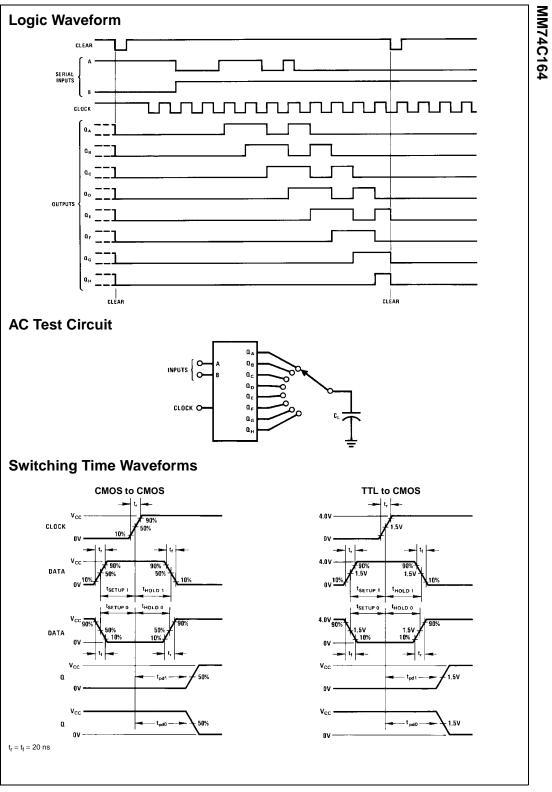
Note 2: AC Parameters are guaranteed by DC correlated testing.

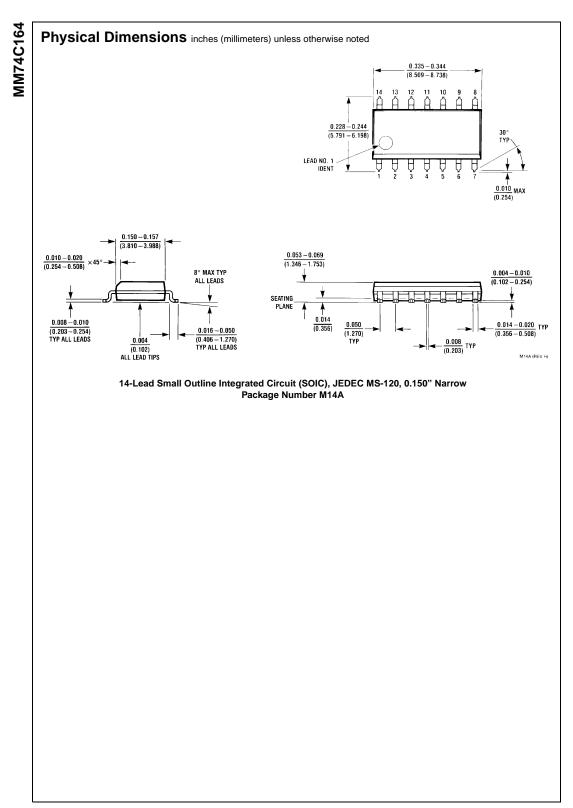
Note 3: Capacitance is guaranteed by periodic testing.

Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics application note AN-90.

Typical Applications







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6

